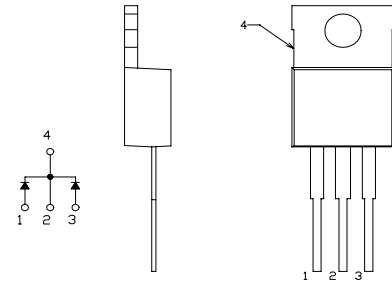


SBD Type : GCQ30A04

OUTLINE DRAWING

FEATURES

- *Similar to TO-220AB Case
- *Dual Diodes – Cathode Common
- *Low Forward Voltage Drop
- *High Surge Capability
- *Tj=150 °C operation



Maximum Ratings

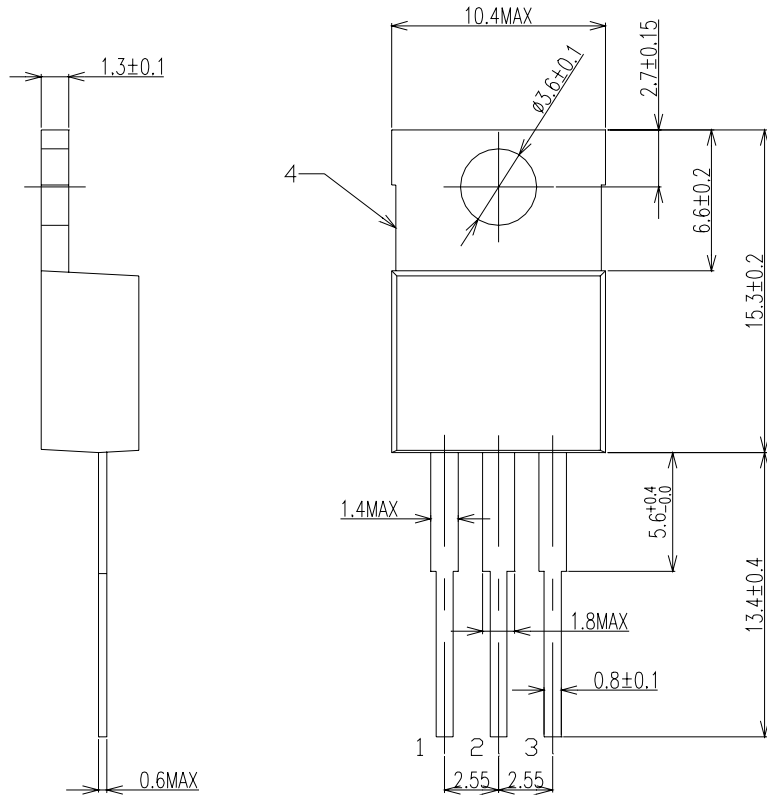
Approx Net Weight: 1.9g

Rating	Symbol	GCQ30A04			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40			V
Average Rectified Output Current	I_O	30	$T_c=104^{\circ}C$	50 Hz Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	33.3			A
Surge Forward Current	I_{FSM}	250	50Hz Full Sine Wave ,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T_{jw}	-40 to +150			°C
Storage Temperature Range	T_{stg}	-40 to +150			°C
Mounting torque	F_{tor}	recommended torque = 0.5			N•m

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j= 25^{\circ}C, V_{RM}= V_{RRM}$ per arm	-	-	15	mA
Peak Forward Voltage	V_{FM}	$T_j= 25^{\circ}C, I_{FM}= 15 A$ per arm	-	-	0.55	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	1.5	°C /W

GCQ30A04 OUTLINE DRAWING (Dimensions in mm)



Center Tap

